nexperia

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Kind regards,

Team Nexperia

PDTA144V series

PNP resistor-equipped transistors; R1 = 47 kΩ, R2 = 10 kΩ

Rev. 04 — 3 September 2009   Product data sheet

1. Product profile

1.1 General description

PNP resistor-equipped transistors.

Table 1.   Product overview

Type number	Package		NPN complement
	NXP	**JEITA**	
PDTA144VE	SOT416	SC-75	PDTC144VE
PDTA144VK	SOT346	SC-59A	PDTC144VK
PDTA144VM	SOT883	SC-101	PDTC144VM
PDTA144VS[1]	SOT54	SC-43A	PDTC144VS
PDTA144VT	SOT23	-	PDTC144VT
PDTA144VU	SOT323	SC-70	PDTC144VU

[1]   Also available in SOT54A and SOT54 variant packages (see Section 2)

1.2 Features

- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs

1.3 Applications

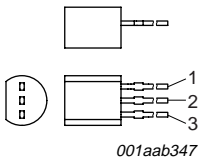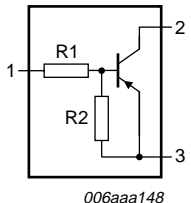- General purpose switching and amplification
- Inverter and interface circuits
- Circuit drivers
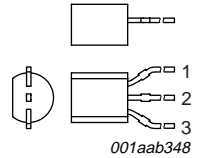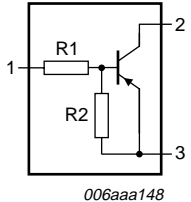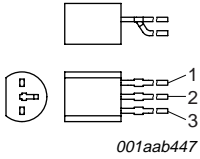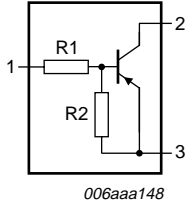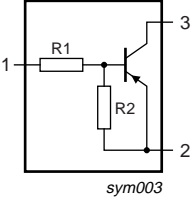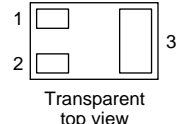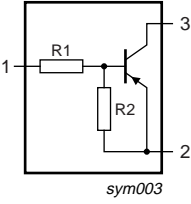
1.4 Quick reference data

Table 2.   Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	−50	V
I_O	output current (DC)		-	-	−100	mA
R1	bias resistor 1 (input)		33	47	61	kΩ
R2/R1	bias resistor ratio		0.17	0.21	0.26	

2. Pinning information

Table 3. Pinning

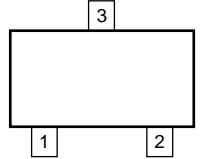| Pin	Description	Simplified outline	Symbol
SOT54			
1	input (base)		
2	output (collector)		
3	GND (emitter)	 *001aab347*	 *006aaa148*
SOT54A			
1	input (base)		
2	output (collector)		
3	GND (emitter)	 *001aab348*	 *006aaa148*
SOT54 variant			
1	input (base)		
2	output (collector)		
3	GND (emitter)	 *001aab447*	 *006aaa148*
SOT23, SOT323, SOT346, SOT416			
1	input (base)		
2	GND (emitter)		
3	output (collector)	 *006aaa144*	 *sym003*
SOT883			
1	input (base)		
2	GND (emitter)		
3	output (collector)	 Transparent top view	 *sym003*

3.   Ordering information

Table 4.   Ordering information

Type number	Package			Version
	Name	**Description**		
PDTA144VE	SC-75	plastic surface mounted package; 3 leads		SOT416
PDTA144VK	SC-59A	plastic surface mounted package; 3 leads		SOT346
PDTA144VM	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 × 0.6 × 0.5 mm		SOT883
PDTA144VS[1]	SC-43A	plastic single-ended leaded (through hole) package; 3 leads		SOT54
PDTA144VT	-	plastic surface mounted package; 3 leads		SOT23
PDTA144VU	SC-70	plastic surface mounted package; 3 leads		SOT323

[1]   Also available in SOT54A and SOT54 variant packages (see Section 2 and Section 9).

4.   Marking

Table 5.   Marking codes

Type number	Marking code[1]
PDTA144VE	13
PDTA144VK	12
PDTA144VM	E9
PDTA144VS	TA144V
PDTA144VT	*AG
PDTA144VU	*12

[1]   * = -: made in Hong Kong

 * = p: made in Hong Kong

 * = t: made in Malaysia

 * = W: made in China

5. Limiting values

Table 6.   Limiting values
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	−50	V
V_{CEO}	collector-emitter voltage	open base	-	−50	V
V_{EBO}	emitter-base voltage	open collector	-	−15	V
V_I	input voltage				
	positive		-	+15	V
	negative		-	−40	V
I_O	output current (DC)		-	−100	mA
I_{CM}	peak collector current		-	−100	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25\ °C$			
	SOT416	[1]	-	150	mW
	SOT346	[1]	-	250	mW
	SOT883	[2][3]	-	250	mW
	SOT54	[1]	-	500	mW
	SOT23	[1]	-	250	mW
	SOT323	[1]	-	200	mW
T_{stg}	storage temperature		−65	+150	°C
T_j	junction temperature		-	150	°C
T_{amb}	ambient temperature		−65	+150	°C

[1]   Refer to standard mounting conditions.

[2]   Reflow soldering is the only recommended soldering method.

[3]   Refer to SOT883 standard mounting conditions; FR4 printed-circuit board with 60 µm copper strip line.

6. Thermal characteristics

Table 7.   Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air				
	SOT416	[1]	-	-	833	K/W
	SOT346	[1]	-	-	500	K/W
	SOT883	[2][3]	-	-	500	K/W
	SOT54	[1]	-	-	250	K/W
	SOT23	[1]	-	-	500	K/W
	SOT323	[1]	-	-	625	K/W

[1]   Refer to standard mounting conditions.

[2]   Reflow soldering is the only recommended soldering method.

[3]   Refer to SOT883 standard mounting conditions; FR4 printed-circuit board with 60 µm copper strip line.

7. Characteristics

Table 8. Characteristics

T_{amb} = 25 °C unless otherwise specified

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{CBO}	collector-base cut-off current	V_{CB} = −50 V; I_E = 0 A	-	-	−100	nA
I_{CEO}	collector-emitter cut-off current	V_{CE} = −30 V; I_B = 0 A	-	-	−1	µA
		V_{CE} = −30 V; I_B = 0 A; T_j = 150 °C	-	-	−50	µA
I_{EBO}	emitter-base cut-off current	V_{EB} = −5 V; I_C = 0 A	-	-	−150	µA
h_{FE}	DC current gain	V_{CE} = −5 V; I_C = −5 mA	40	-	-	
V_{CEsat}	collector-emitter saturation voltage	I_C = −10 mA; I_B = −0.5 mA	-	-	−150	mV
$V_{I(off)}$	off-state input voltage	V_{CE} = −5 V; I_C = −100 µA	-	−3.1	−1	V
$V_{I(on)}$	on-state input voltage	V_{CE} = −300 mV; I_C = −2 mA	−6	−3.8	-	V
R1	bias resistor 1 (input)		33	47	61	kΩ
R2/R1	bias resistor ratio		0.17	0.21	0.26	
C_c	collector capacitance	V_{CB} = −10 V; I_E = i_e = 0 A; f = 1 MHz	-	-	2	pF

006aaa111
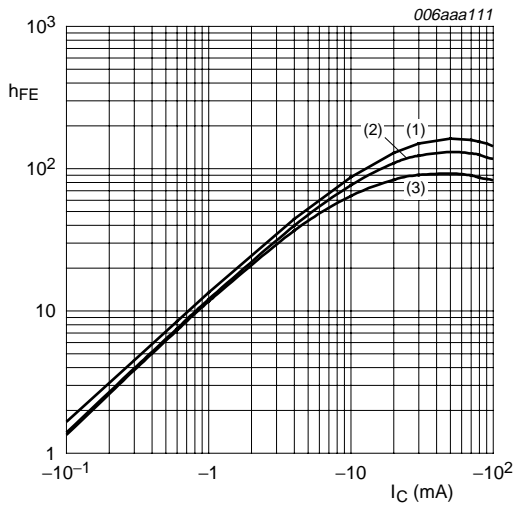
$V_{CE} = -5$ V

(1) $T_{amb} = 100$ °C

(2) $T_{amb} = 25$ °C

(3) $T_{amb} = -40$ °C

Fig 1.   DC current gain as a function of collector current; typical values

006aaa112
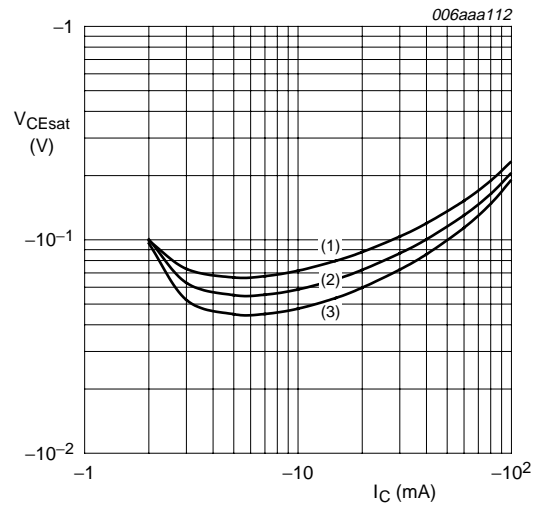
$I_C/I_B = 20$

(1) $T_{amb} = 100$ °C

(2) $T_{amb} = 25$ °C

(3) $T_{amb} = -40$ °C

Fig 2.   Collector-emitter saturation voltage as a function of collector current; typical values

006aaa113
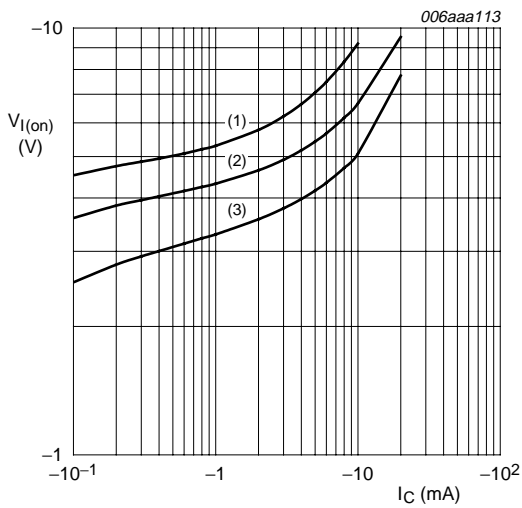
$V_{CE} = -0.3$ V

(1) $T_{amb} = -40$ °C

(2) $T_{amb} = 25$ °C

(3) $T_{amb} = 100$ °C

Fig 3.   On-state input voltage as a function of collector current; typical values

006aaa114
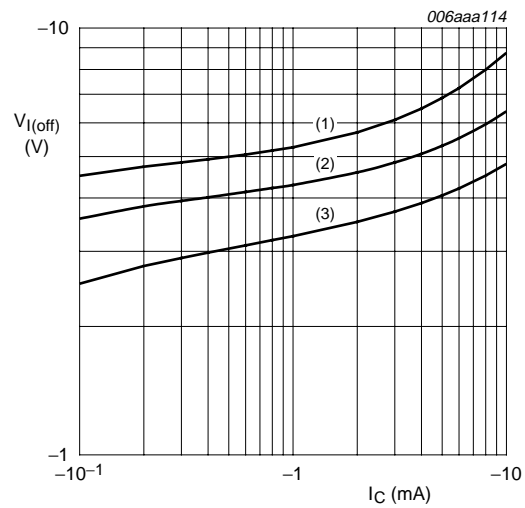
$V_{CE} = -5$ V

(1) $T_{amb} = -40$ °C

(2) $T_{amb} = 25$ °C

(3) $T_{amb} = 100$ °C

Fig 4.   Off-state input voltage as a function of collector current; typical values

8. Package outline

Plastic surface-mounted package; 3 leads   **SOT416**

DIMENSIONS (mm are the original dimensions)

UNIT	A	A$_1$ max	bp	c	D	E	e	e$_1$	H$_E$	L$_p$	Q	v	w
mm	0.95 0.60	0.1	0.30 0.15	0.25 0.10	1.8 1.4	0.9 0.7	1	0.5	1.75 1.45	0.45 0.15	0.23 0.13	0.2	0.2

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT416			SC-75			~~04-11-04~~ 06-03-16

Fig 5.   Package outline SOT416 (SC-75)

PDTA144V_SER_4
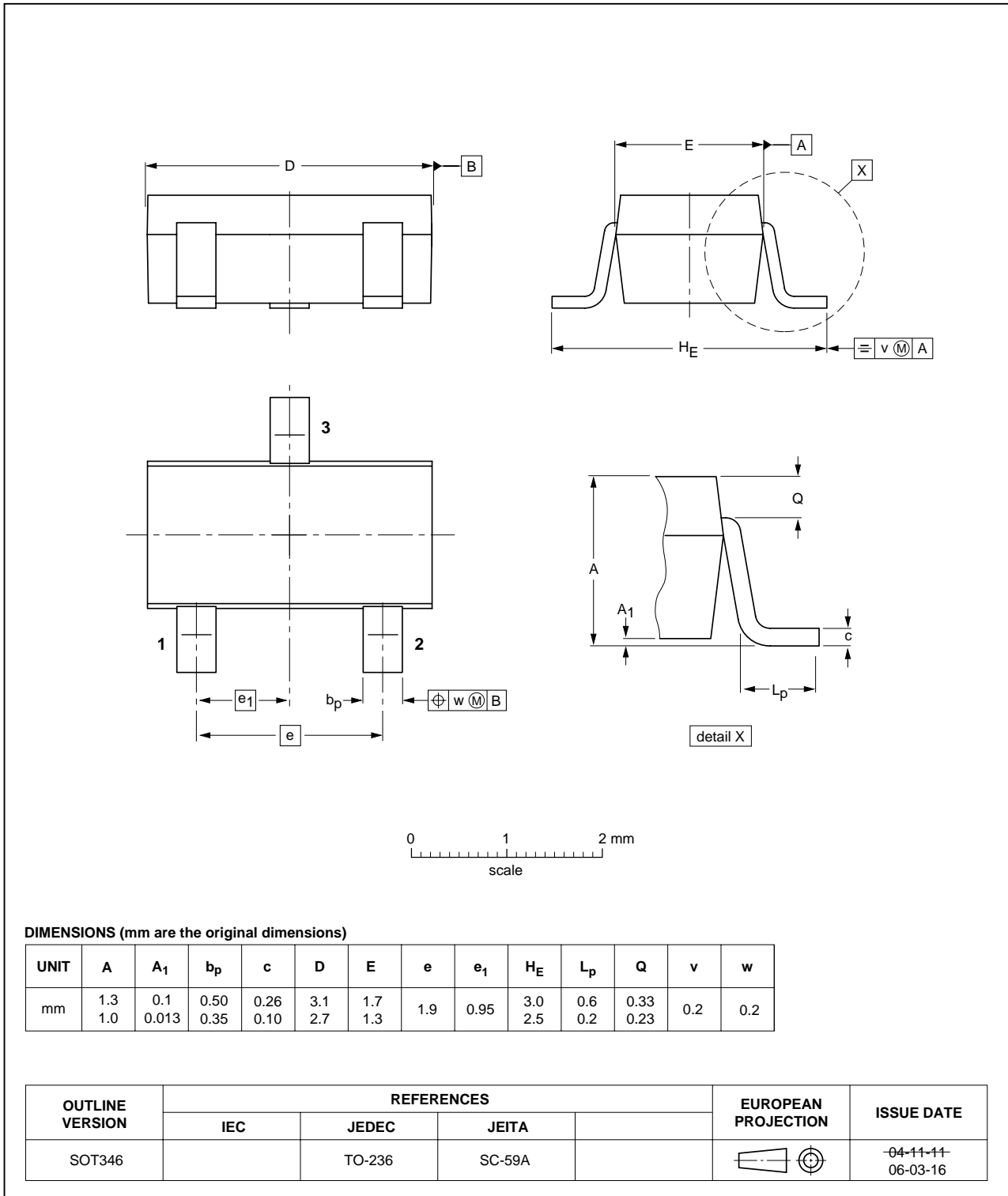
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Plastic surface-mounted package; 3 leads

SOT346

DIMENSIONS (mm are the original dimensions)

UNIT	A	A$_1$	b$_p$	c	D	E	e	e$_1$	H$_E$	L$_p$	Q	v	w
mm	1.3 1.0	0.1 0.013	0.50 0.35	0.26 0.10	3.1 2.7	1.7 1.3	1.9	0.95	3.0 2.5	0.6 0.2	0.33 0.23	0.2	0.2

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT346		TO-236	SC-59A			~~04-11-11~~ 06-03-16

Fig 6.   Package outline SOT346 (SC-59A/TO-236)

PDTA144V_SER_4

Product data sheet

Rev. 04 — 3 September 2009

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PNP resistor-equipped transistors; R1 = 47 kΩ, R2 = 10 kΩ

Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.5 mm

SOT883

DIMENSIONS (mm are the original dimensions)

UNIT	A[1]	A$_1$ max.	b	b$_1$	D	E	e	e$_1$	L	L$_1$
mm	0.50 0.46	0.03	0.20 0.12	0.55 0.47	0.62 0.55	1.02 0.95	0.35	0.65	0.30 0.22	0.30 0.22

Note

1. Including plating thickness

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT883			SC-101			~~03-02-05~~ 03-04-03

Fig 7. Package outline SOT883 (SC-101)

PNP resistor-equipped transistors; R1 = 47 kΩ, R2 = 10 kΩ

Plastic single-ended leaded (through hole) package; 3 leads   **SOT54**

DIMENSIONS (mm are the original dimensions)

UNIT	A	b	b$_1$	c	D	d	E	e	e$_1$	L	L$_1$[(1)] max.
mm	5.2 5.0	0.48 0.40	0.66 0.55	0.45 0.38	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

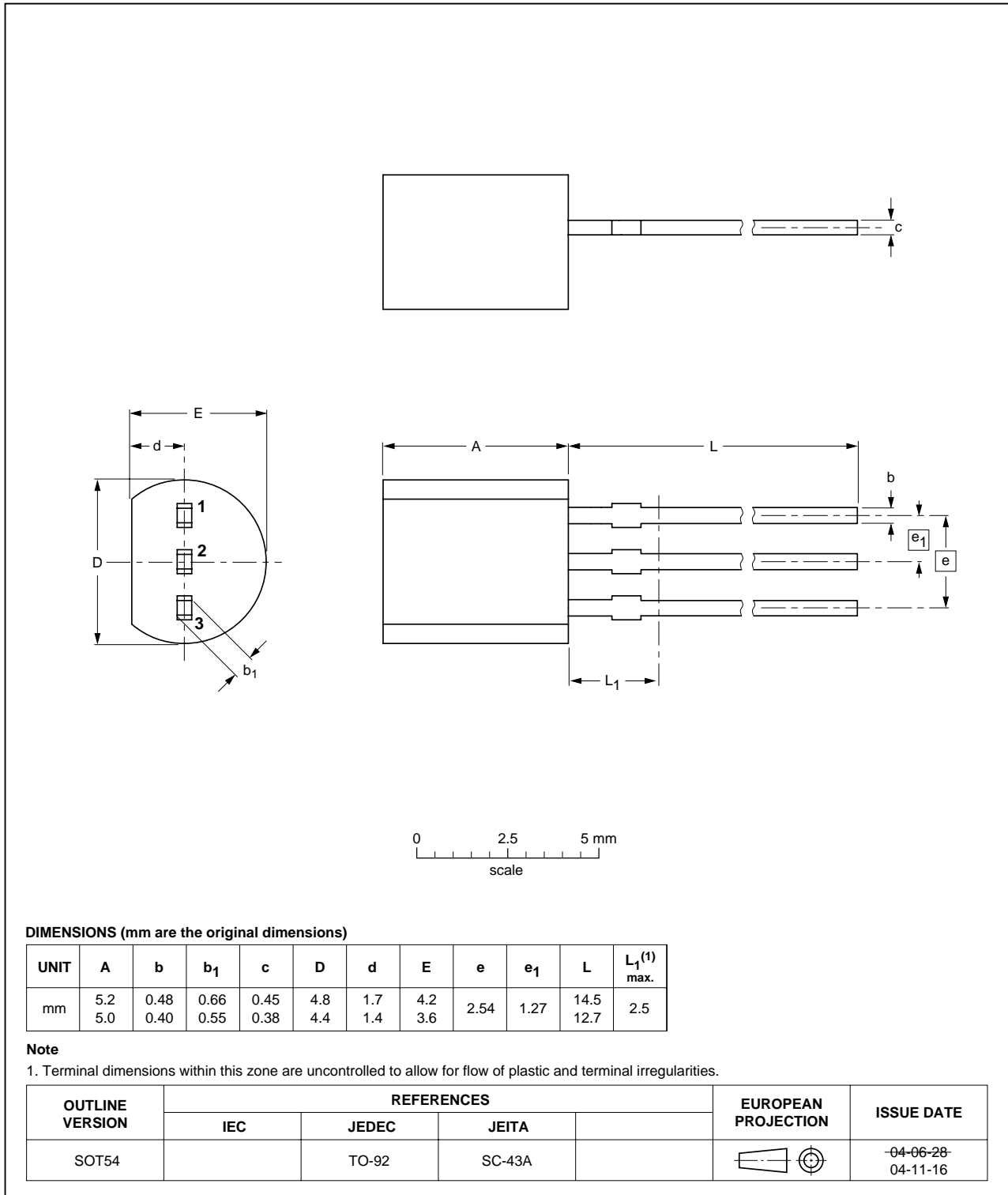| OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT54		TO-92	SC-43A			~~04-06-28~~ 04-11-16

Fig 8.   Package outline SOT54 (SC-43A/TO-92)

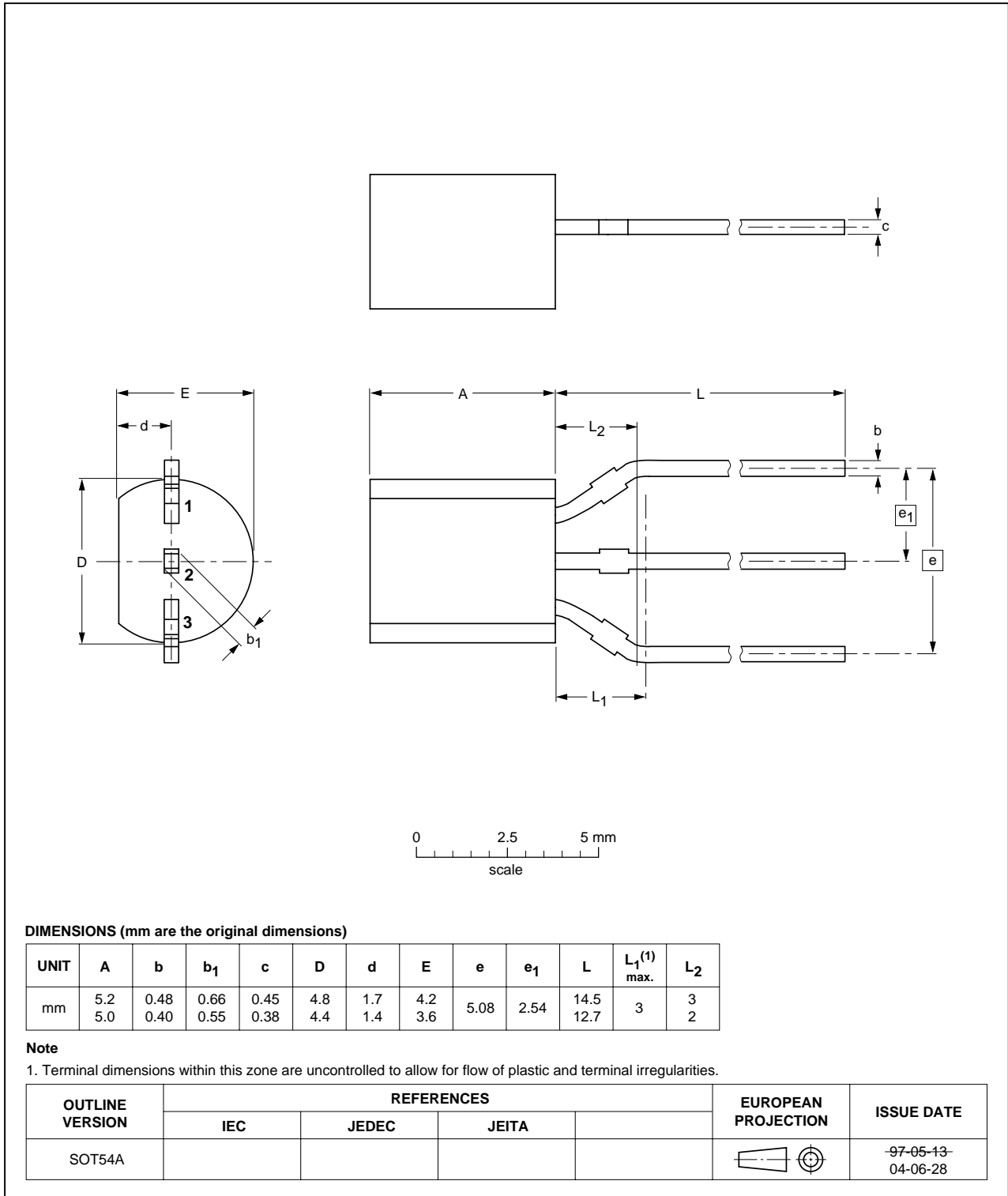**Plastic single-ended leaded (through hole) package; 3 leads (wide pitch)**

SOT54A

DIMENSIONS (mm are the original dimensions)

UNIT	A	b	b₁	c	D	d	E	e	e₁	L	L₁(1) max.	L₂
mm	5.2 5.0	0.48 0.40	0.66 0.55	0.45 0.38	4.8 4.4	1.7 1.4	4.2 3.6	5.08	2.54	14.5 12.7	3	3 2

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT54A						~~97-05-13~~ 04-06-28

Fig 9. Package outline SOT54A

PNP resistor-equipped transistors; R1 = 47 kΩ, R2 = 10 kΩ

Plastic single-ended leaded (through hole) package; 3 leads (on-circle)   **SOT54 variant**

DIMENSIONS (mm are the original dimensions)

UNIT	A	b	b₁	c	D	d	E	e	e₁	L	L₁(1) max	L₂ max
mm	5.2 5.0	0.48 0.40	0.66 0.55	0.45 0.38	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5	2.5

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT54 variant						04-06-28 05-01-10

Fig 10. Package outline SOT54 variant

PNP resistor-equipped transistors; R1 = 47 kΩ, R2 = 10 kΩ

Plastic surface-mounted package; 3 leads   **SOT23**

DIMENSIONS (mm are the original dimensions)

UNIT	A	A₁ max.	bp	c	D	E	e	e₁	HE	Lp	Q	v	w
mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT23		TO-236AB				~~04-11-04~~ 06-03-16

Fig 11. Package outline SOT23 (TO-236AB)

PDTA144V_SER_4

PNP resistor-equipped transistors; R1 = 47 kΩ, R2 = 10 kΩ

Plastic surface-mounted package; 3 leads SOT323

DIMENSIONS (mm are the original dimensions)

UNIT	A	A$_1$ max	b$_p$	c	D	E	e	e$_1$	H$_E$	L$_p$	Q	v	w
mm	1.1 0.8	0.1	0.4 0.3	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.23 0.13	0.2	0.2

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT323			SC-70			04-11-04 06-03-16

Fig 12. Package outline SOT323 (SC-70)

PDTA144V_SER_4

9. Packing information

Table 9.   Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code. [1]

Type number	Package	Description	Packing quantity		
			3000	**5000**	**10000**
PDTA144VE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135
PDTA144VK	SOT346	4 mm pitch, 8 mm tape and reel	-115	-	-135
PDTA144VM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315
PDTA144VS	SOT54	bulk, straight leads	-	-412	-
	SOT54A	tape and reel, wide pitch	-	-	-116
		tape ammopack, wide patch	-	-	-126
	SOT54 variant	bulk, delta pinning	-	-112	-
PDTA144VT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235
PDTA144VU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135

[1]   For further information and the availability of packing methods, see Section 12.

10. Revision history

Table 10.   Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PDTA144V_SER_4	20090903	Product data sheet	-	PDTA144V_SER_3
Modifications:	• This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content			
	• Figure 5 "Package outline SOT416 (SC-75)":updated			
	• Figure 6 "Package outline SOT346 (SC-59A/TO-236)": updated			
	• Figure 11 "Package outline SOT23 (TO-236AB)": updated			
	• Figure 12 "Package outline SOT323 (SC-70)": updated			
PDTA144V_SER_3	20050222	Product data sheet	-	PDTA144VT_2
PDTA144VT_2	20040514	Objective data sheet	-	PDTA144VT_1
PDTA144VT_1	20040305	Objective data sheet	-	-

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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13. Contents

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